IN THE SPECIFICATION

Please amend Table 2 on page 32 as follows:

Table 2

	Zirconium chelate complex	Pyrolysis temperature [°C]	
Example 13	Zr(dhd)3(thd)	260	
Example 14	Zr(dhd)2(thd)2	280	
Example 15	Zr(dhd)(thd) ₃	Zr(dhd)(thd) ₃ 300	
Comparative Example 7	Zr(thd) ₄	410	
-	Pd(thd)2 Pb(thd)2	325	
-	Ti(iPrO) ₂ (thd) ₂	280	

Please amend Table 6 on page 36 as follows:

Table 6

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	Zr chelate complex	Pb chelate complex	Ti chelate complex	Organic solvent	Residue ratio [%]
		Pd(thd) ₂			-
Example 13	$Zr(dhd)_3(thd)$	$Pb(thd)_2$	-	THF	0.1
		Pd(thd) ₂			
	$Zr(dhd)_3(thd)$	Pb(thd) ₂	Ti(iPrO) ₂ (thd) ₂	THF	0.2
	Zr(dhd)3(thd)	Pd(thd) ₂		СуНех	0.1
		$\frac{Pb(thd)_2}{Pb(thd)_2}$	-		
		Pd(thd) ₂			
	Zr(dhd) ₃ (thd)	$\frac{Pb(thd)_2}{Pb(thd)_2}$	$Ti(iPrO)_2(thd)_2$	СуНех	0.2
	$Zr(dhd)_2(thd)_2$	Pd(thd) ₂		THF	0.1
		$\frac{Pb(thd)_2}{Pb(thd)_2}$	-		
		Pd(thd) ₂		THF	0.2
	$Zr(dhd)_2(thd)_2$	$Pb(thd)_2$	$Ti(iPrO)_2(thd)_2$		
Example 14		Pd(thd) ₂	-	СуНех	
	$Zr(dhd)_2(thd)_2$	$\frac{Pb(thd)_2}{P}$			0.1
	Zr(dhd) ₂ (thd) ₃	Pd(thd) ₂	Ti(iPrO) ₂ (thd) ₂	СуНех	
:		$Pb(thd)_2$			0.2
Example 15	Zr(dhd)(thd) ₃	Pd(thd) ₂		THF	0.1
		$Pb(thd)_2$	-		
	Zr(dhd)(thd) ₃	Pd(thd) ₂	T:('D (0) (41 1)	THF	0.2
		$Pb(thd)_2$	$Ti(iPrO)_2(thd)_2$		
	Zr(dhd)(thd) ₃	Pd(thd) ₂		СуНех	0.1
		$Pb(thd)_2$	-		
	Zr(dhd)(thd) ₃	Pd(thd) ₂	T'('D O) (41.4)	СуНех	0.2
		$Pb(thd)_2$	$Ti(iPrO)_2(thd)_2$		0.2
Comparative Example 11	Zr(iPrO)(thd) ₃	Pd(thd)2		THF	2.0
		$Pb(thd)_2$	-		
	Zr(iPrO)(thd) ₃	Pd(thd)2	T;(;D=O) (thd)	THF	6.3
		$Pb(thd)_2$	Ti(iPrO) ₂ (thd) ₂		0.3
Comparative	7r(nD110)(+h.d)	Pd(thd)2	Ti(iPrO) ₂ (thd) ₂	THF	7.1
Example 12	$Zr(nBuO)(thd)_3$	$Pb(thd)_2$	11(1110)2(11111)2	1ПГ	7.1

Please amend Table 8 on page 41 as follows:

Table 8

Film forming temperature	420 to 620°C	Organolead compound	Pb(thd) ₂ Pd(thd) ₂	
		<u> </u>		
Film forming time	150 to 200 sec	Organotitanium compound	Ti(iPrO) ₂ (thd) ₂	
Reaction pressure	532 Pa (4 Torr)	Flow rate of lead solution	of lead 0.40 ml/min	
Vaporization temperature	210°C	Flow rate of Zr solution	0.35 ml/min	
Flow rate of oxygen gas	2.5 slm	Flow rate of titanium solution	0.12 ml/min	
Flow rate of He gas (Carrier gas)	250 sccm	Substrate	PbTiO ₃ PdTiO ₂ /Pt/SiO ₂ /Si (5 nm/200 nm/500 nm)	
Concentration of raw material solution	0.3 mol/l			